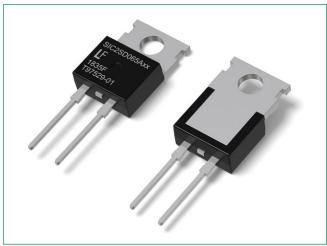


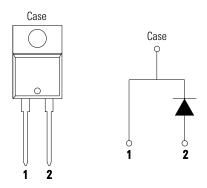
LSIC2SD065A10A 650 V, 10 A SiC Schottky Barrier Diode





*Image for reference only, for details refer to Dimensions-Package

Circuit Diagram TO-220-2L



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo =**HF**Halogen Free
- Littelfuse "Pb-free" logoPb-free lead plating



Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Citalacteristics	Зушьог	Conditions	value	Oill	
Repetitive Peak Reverse Voltage	V _{RRM}	V _{RRM} -		V	
DC Blocking Voltage	V _R	T _J = 25 °C	650	V	
Continuous Forward Current		T _c = 25 °C	27		
	I _F	T _C = 135 °C	12.5	Α	
		T _C = 147 °C	10		
Non-Repetitive Forward Surge Current	FSM	$T_{\rm C}$ = 25 °C, $T_{\rm P}$ = 10 ms, Half sine pulse	48	А	
Power Dissipation	D	T _C = 25 °C	100	W	
	P _{Tot}	T _C = 110 °C	43		
Operating Junction Temperature	T _J	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{SOLD}	-	260	°C	



Electrical Characteristics (T_J =25 °C unless otherwise specified)

Characteristics	Complete	Conditions	Value			Unit
Characteristics Symbol		Conditions	Min.	Тур.	Max.	Unit
Forward Voltage	V _F	$I_F = 10 \text{ A}, T_J = 25 ^{\circ}\text{C}$	-	1.5	1.8	· V
		$I_F = 10 \text{ A}, T_J = 175 ^{\circ}\text{C}$	-	1.85	-	
Reverse Current	I _R -	$V_R = 650 \text{ V}$, $T_J = 25 \text{ °C}$	-	<1	50	μΑ
		$V_R = 650 V$, $T_J = 175 ^{\circ}C$	-	25	-	
Total Capacitance	С	$V_R = 1 V$, $f = 1 MHz$	-	470	-	pF
		$V_R = 200 V_r f = 1 MHz$	-	60	-	
		$V_R = 400 V$, $f = 1 MHz$	-	43	-	
Total Capacitive Charge	Q_c	$V_{R} = 400 \text{ V, } Q_{c} = \begin{cases} V_{R} \\ C(V) dV \\ 0 \end{cases}$	-	30	-	nC

Thermal Characteristics

Characteristics	Symbol	Value	Unit
Thermal Resistance	R _{e.ic}	1.5	°C/W

Figure 1: Typical Foward Characteristics

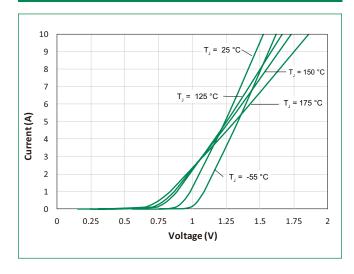


Figure 2: Typical Reverse Characteristics

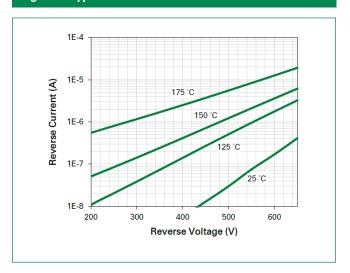




Figure 3: Power Derating

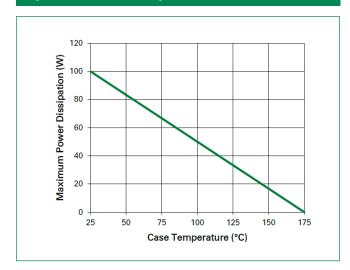


Figure 4: Current Derating

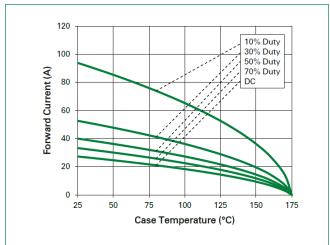


Figure 5: Capacitance vs. Reverse Voltage

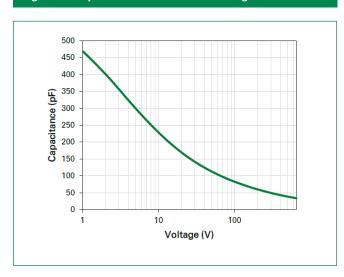


Figure 6: Capacitive Charge vs. Reverse Voltage

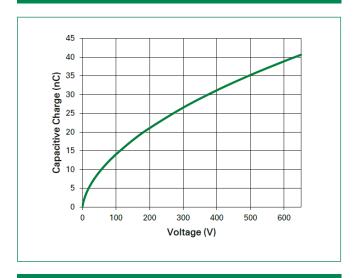


Figure 7: Stored Energy vs. Reverse Voltage

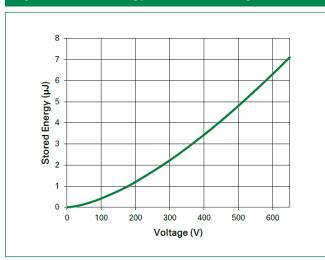
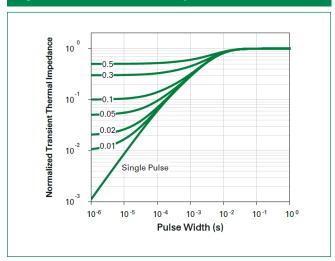
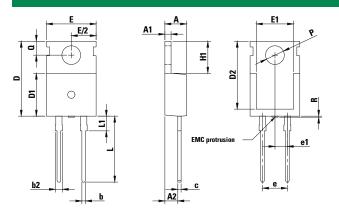


Figure 8: Transient Thermal Impedance

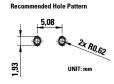


GEN2 SiC Schottky Diode LSIC2SD065A10A, 650V, 10A, TO-220-2L

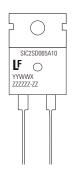
Dimensions-Package TO-220-2L



Compleal	Millimeters				
Symbol	Min	Nom	Max		
Α	4.30	4.45	4.70		
A1	1.14	1.27	1.40		
A2	2.20	-	2.74		
b	0.69	-	0.90		
b2	1.17	-	1.62		
С	0.36	-	0.60		
D	14.90	-	15.90		
D1	8.62	-	9.40		
D2	12.50	-	12.95		
E	9.70	10.18	10.36		
E1	7.57	7.61	8.30		
e1	-	2.54	-		
е	5.03	5.08	5.13		
H1	6.30	6.55	6.80		
L	12.88	13.50	14.00		
L1	2.39	-	3.25		
øΡ	3.50	3.84	3.96		
Q	2.65	-	3.05		
R	-	-	0.25		



Part Numbering and Marking System



SIC = SiC Diode
2 = Gen2
SD = Schottky Diode
065 = Voltage Rating (650 V)
A = T0-220 Package (2 Lead)
10 = Current Rating (10 A)
YY = Year
WW = Week
X = Special Code

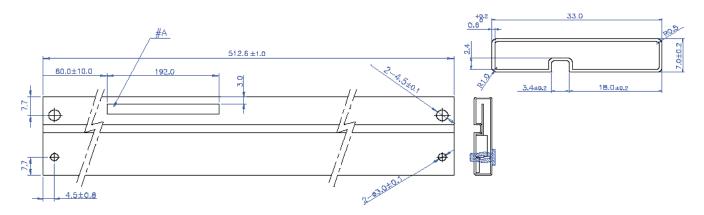
ZZZZZZ-ZZ = Lot Number

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065A10A	SIC2SD065A10	Tube(50pcs)	1000

GEN2 SiC Schottky Diode LSIC2SD065A10A, 650V, 10A, TO-220-2L

Packing Specification (Tube for TO-220-2L)



[NOTE]

- 1. TUBE MATERIAL : PVC / PET (WITH ANTISTATIC COATING)
 - COLOR: TRANSPARENCY, RED, YELLO
 - MARKING #A : BLACK COLOR, LETTER STYLE : Arial
 - Tube Surface Resistance $:10^6 \sim 10^{11} \,\Omega$ /square
 - ESD (Electro Static Discharge) : less than 100 [volts], 6 Months
 - CAMBAR : 1.5 MAX
- 2. PIN COLOR : GREEN (ONE PIN MUST BE INSERTED IN LEFT-SIDE OF " \square ANTISTATIC~" AND ANOTHER PIN IS FREE.)